

## N-Ch SiC Power MOSFET

$V_{DS}=1700V$

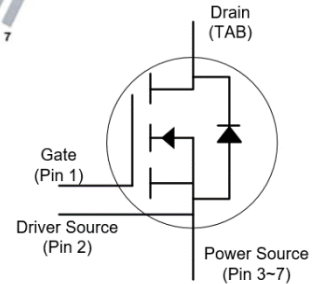
$I_D=5A$  ( $T_c=25^\circ C$ )

$R_{DS}=710m\Omega$  ( $V_{GS}=15V, T_J=25^\circ C$ )

### Features:

- Low On-Resistance with High Blocking Voltage
- Low Capacitance
- Halogen Free, Rohs Compliant

TO-263- 7L



### Benefits:

- High Frequency Operation
- Enabling Higher Switching Frequency
- Increased Power Density
- Reduction of Heat Sink Requirements

### Applications:

- Switch Mode Power Supplies (SMPS)
- Auxiliary power supplies
- High-voltage capacitive loads

### Maximum Rated Valued of MOSFET

Drain-source voltage	$V_{DSS}$		1700	V
Recommend Gate-Source Voltage	$V_{GSop}$		-5/12...15	V
Gate-Source Voltage	$V_{GSmax}$	AC( $f > 1KHz$ )	-10/25	V
Continuous drain current	$I_D$	$V_{GS}=15V, T_c=100^\circ C$	3.5	A
		$V_{GS}=15V, T_c=25^\circ C$	5	A
Pulsed drain current	$I_{DM}$	$t_{Pulse}$ limited by $T_{jmax}$	12	A
Maximum power dissipation	$P_{tot}$	$T_c=25^\circ C, T_J=150^\circ C$	70	W
Operating Junction Temperature	$T_J$		-55~150	$^\circ C$
Storage Temperature	$T_{stg}$		-55~150	$^\circ C$

### Thermal Characteristic

Thermal resistance, junction-to-case	$R_{\theta JC}$		1.78	$^\circ C/W$
Thermal resistance, junction-to-ambient	$R_{\theta JA}$		62.5	$^\circ C/W$

## Electrical Characteristics of MOSFET

				Min.	Typ.	Max.	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D=250\mu A, V_{GS}=0V$	$T_J=25^\circ C$	1700	-	-	V
Gate threshold voltage	$V_{GS(th)}$	$I_D=5mA, V_{DS}=V_{GS}$	$T_J=25^\circ C$	2.0	2.9	4.0	V
			$T_J=150^\circ C$	-	2.0	-	
Zero gate voltage drain current	$I_{DSS}$	$V_{DS}=1700V, V_{GS}=0V$	$T_J=25^\circ C$	-	-	100	$\mu A$
Gate-Source leakage current	$I_{GSSF}$	$V_{DS}=0V, V_{GS}=20V$	$T_J=25^\circ C$	-	-	200	nA
	$I_{GSSR}$	$V_{DS}=0V, V_{GS}=-4V$	$T_J=25^\circ C$	-	-	-200	nA
Drain-Source On-State resistance	$R_{DS(ON)}$	$V_{GS}=15V, I_D=2A$	$T_J=25^\circ C$	-	710	850	$m\Omega$
			$T_J=150^\circ C$	-	1010	-	$m\Omega$
		$V_{GS}=12V, I_D=2A$	$T_J=25^\circ C$	-	1040	1200	$m\Omega$
			$T_J=150^\circ C$	-	1230	-	$m\Omega$
Transconductance	$g_{fs}$	$V_{DS}=20V, I_D=2A$	$T_J=25^\circ C$	-	7.3	-	S
Internal gate resistance	$R_{Gint}$	$f=1MHz, V_{AC}=25mV$	$T_J=25^\circ C$	-	20	-	$\Omega$
Input capacitance	$C_{iss}$	$f=1MHz, V_{DS}=1000V, V_{GS}=0V, V_{AC}=25mV$	$T_J=25^\circ C$	-	380	-	pF
Output capacitance	$C_{oss}$		$T_J=25^\circ C$	-	14	-	pF
Reverse transfer capacitance	$C_{rss}$		$T_J=25^\circ C$	-	3.2	-	pF
Gate to source charge	$Q_{GS}$	$V_{DS}=800V$	$T_J=25^\circ C$	-	4.8	-	nC
Gate to drain charge	$Q_{GD}$	$I_D=2A$	$T_J=25^\circ C$	-	5.6	-	nC
Total gate charge	$Q_G$	$V_{GS}=-5V/20V$	$T_J=25^\circ C$	-	13	-	nC
Turn-on delay time	$t_{don}$	$V_{DS}=1200V, I_{DS}=2A, R_{G-ext}=2.5\Omega, V_{GS}=-5V/20V,$	$T_J=25^\circ C$	-	6	-	ns
Rise time	$t_r$		$T_J=25^\circ C$	-	9.5	-	ns
Turn-off delay time	$t_{doff}$		$T_J=25^\circ C$	-	14	-	ns
Fall time	$t_f$		$T_J=25^\circ C$	-	23	-	ns
Turn-on energy loss per pulse	$E_{on}$		$T_J=25^\circ C$	-	37	-	$\mu J$
Turn-off energy loss per pulse	$E_{off}$		$T_J=25^\circ C$	-	15	-	$\mu J$

## Characteristics of Body Diode

				Min.	Typ.	Max.	
Forward voltage	$V_{SD}$	$I_{SD}=1A, V_{GS}=-4V$	$T_J=25^\circ C$	-	3.5	-	V
Continuous diode forward current	$I_S$		$T_J=25^\circ C$	-	-	4	A
Peak reverse recovery current	$I_{RM}$	$V_R=1200V, I_{SD}=2A,$	$T_J=150^\circ C$	-	3.5	-	A
Reverse recovery time	$t_{rr}$	$V_{GS}=-5V$	$T_J=150^\circ C$	-	22	-	ns
Recovery charge	$Q_{rr}$	$-di/dt=1200A/\mu s$	$T_J=150^\circ C$	-	31	-	nC

Fig.1 Typical Forward Output Characteristics at  $T_J=25^\circ\text{C}$

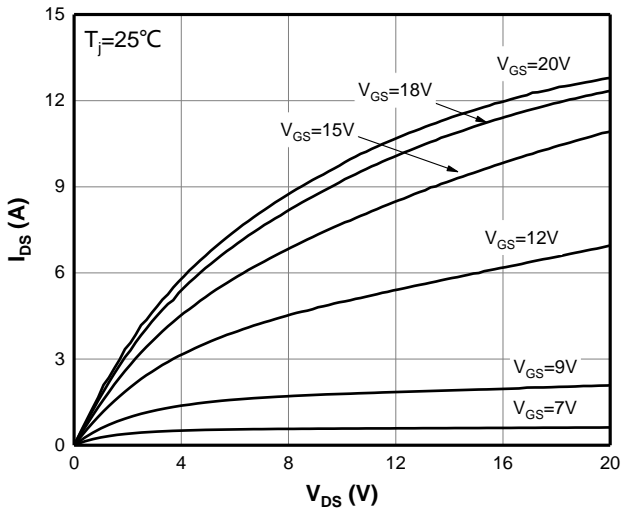


Fig.2 Typical Forward Output Characteristics at  $T_J=150^\circ\text{C}$

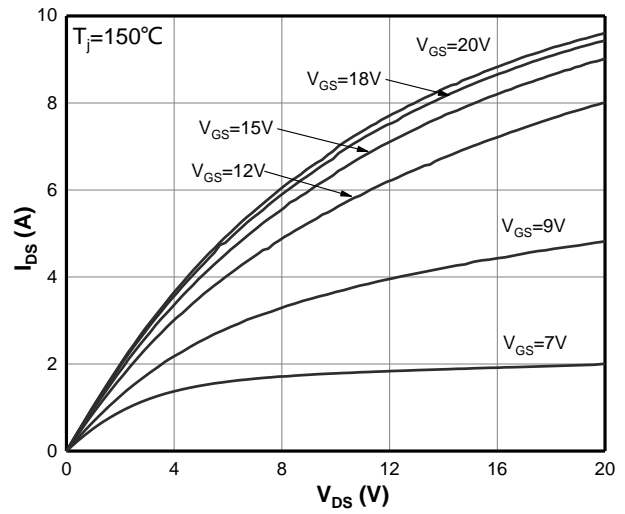


Fig.3 Transfer Characteristics for Various Temperature

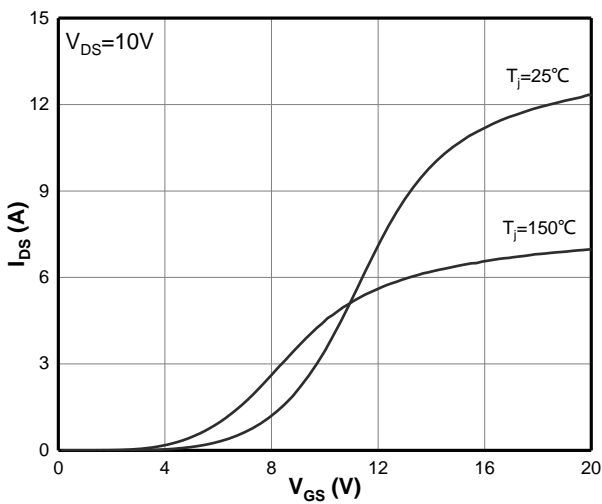


Fig.4 Threshold Voltage for Various Temperature

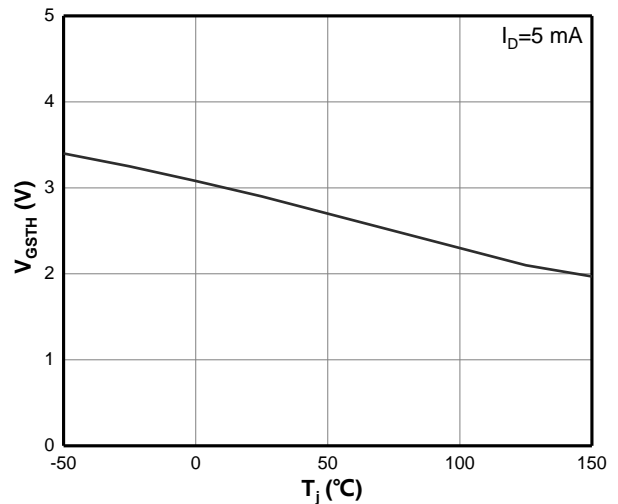


Fig.5 Normalized On-Resistance vs. Temperature for Various Gate Voltage

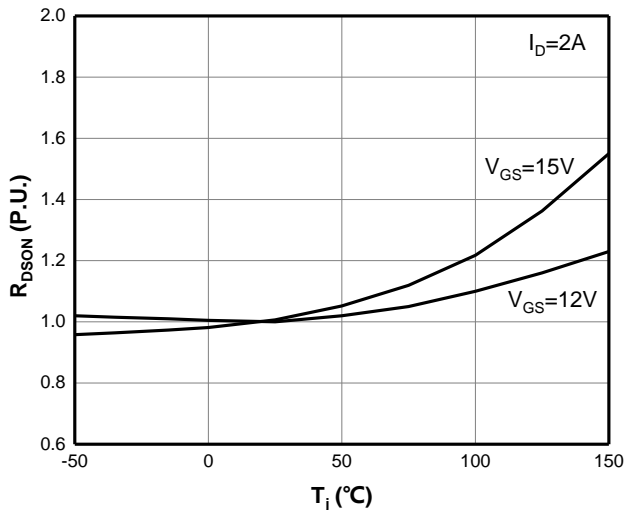


Fig.6 On-Resistance vs. Temperature for Various Gate Voltage

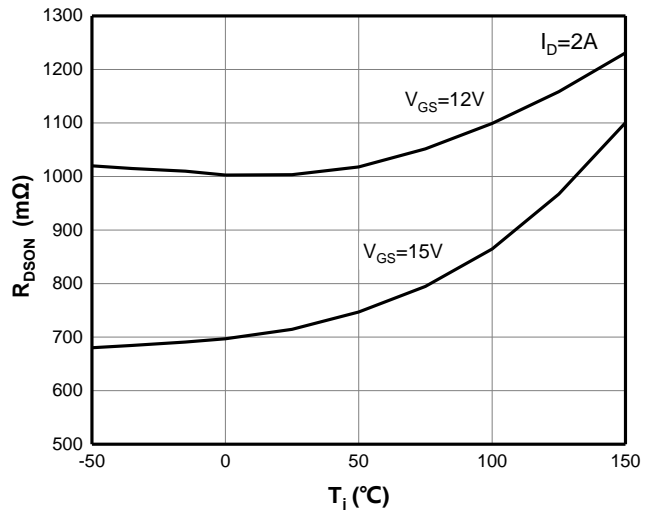


Fig.7 Breakdown voltage vs. Temperature

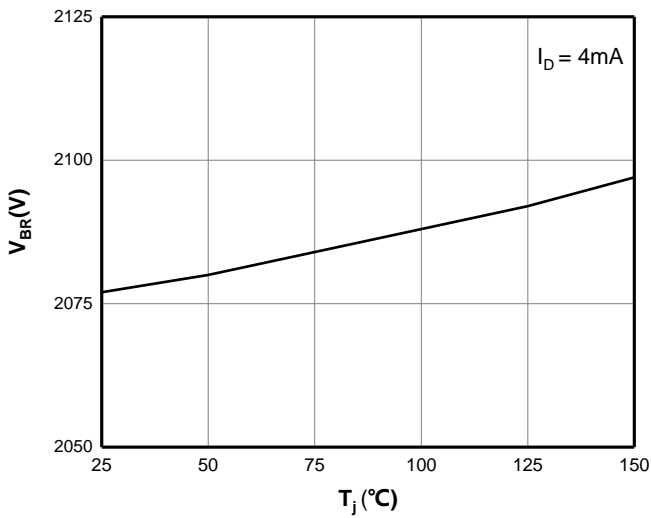


Fig.9 Capacitance vs. Drain-Source Voltage

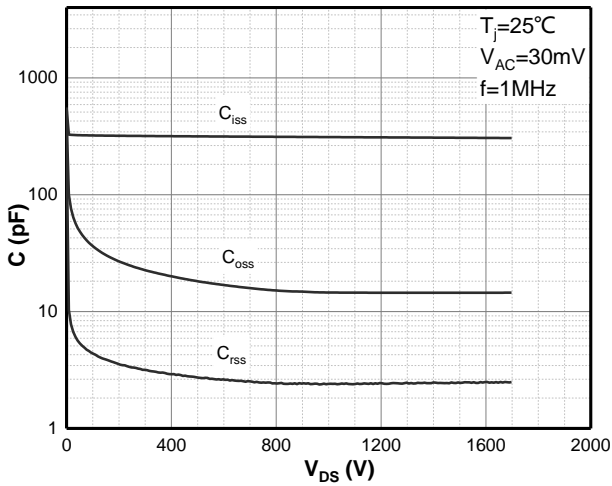


Fig.11 Continuous Drain Current Derating vs. Case Temperature

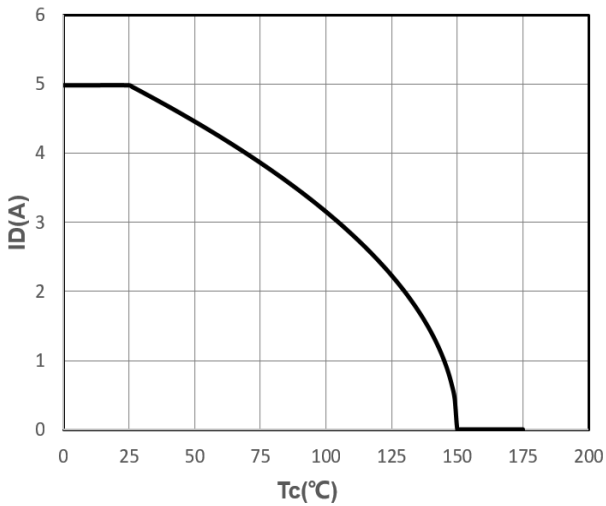


Fig.8 Body Diode Characteristics

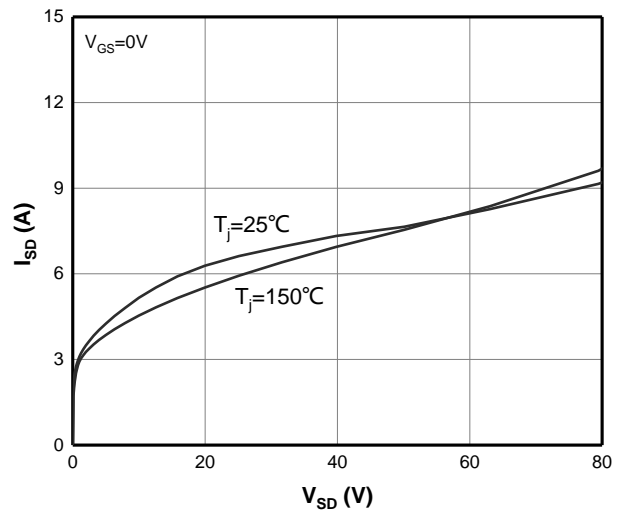


Fig.10 Gate Charge Characteristics

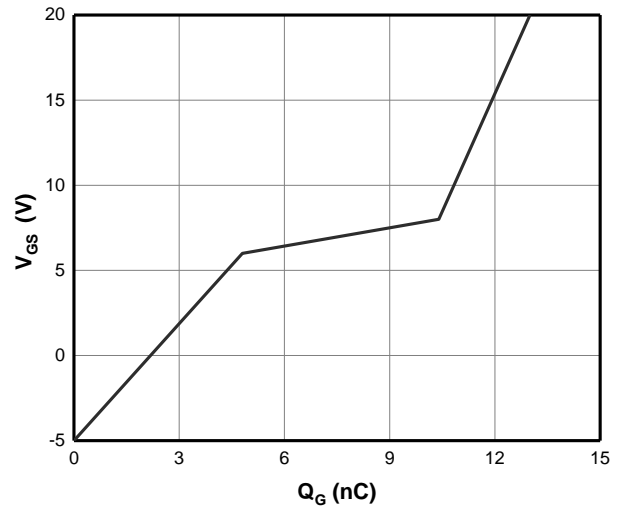


Fig.12 Clamped inductive switching energy vs. temperature

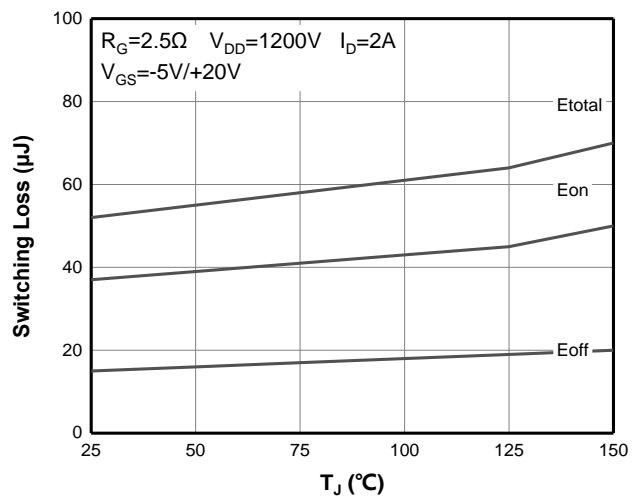


Fig.13 Clamped Inductive Switching Energy vs. External Gate Resistance

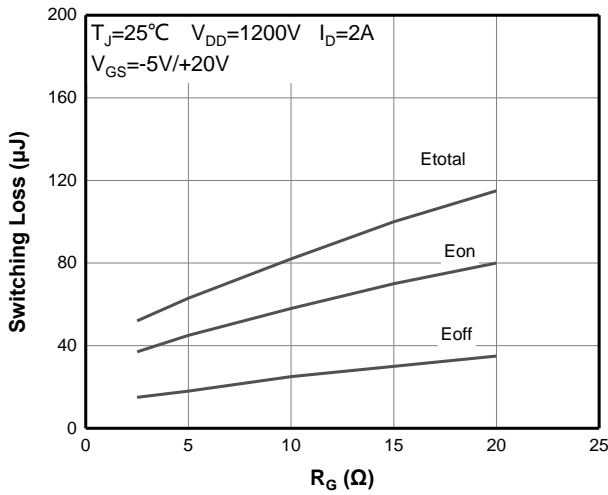


Fig.13 Safe Operating Area

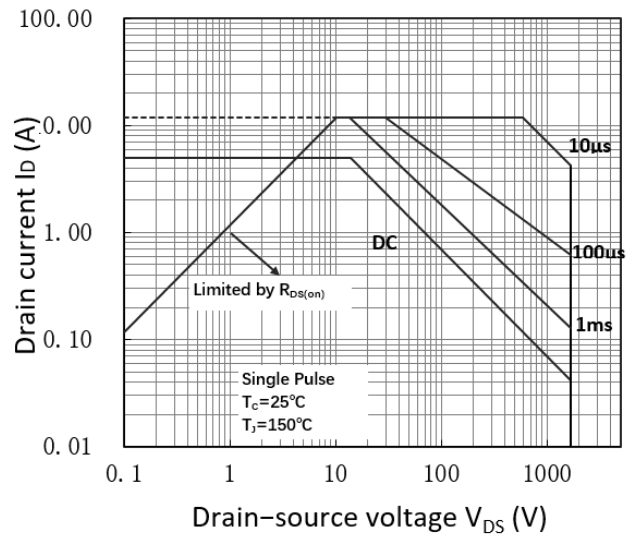
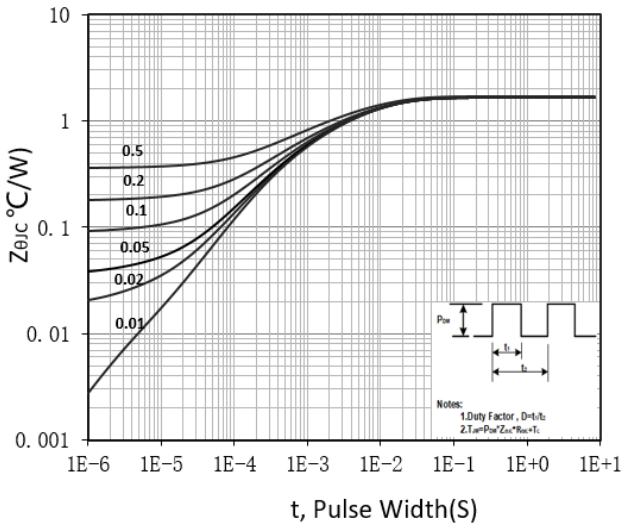
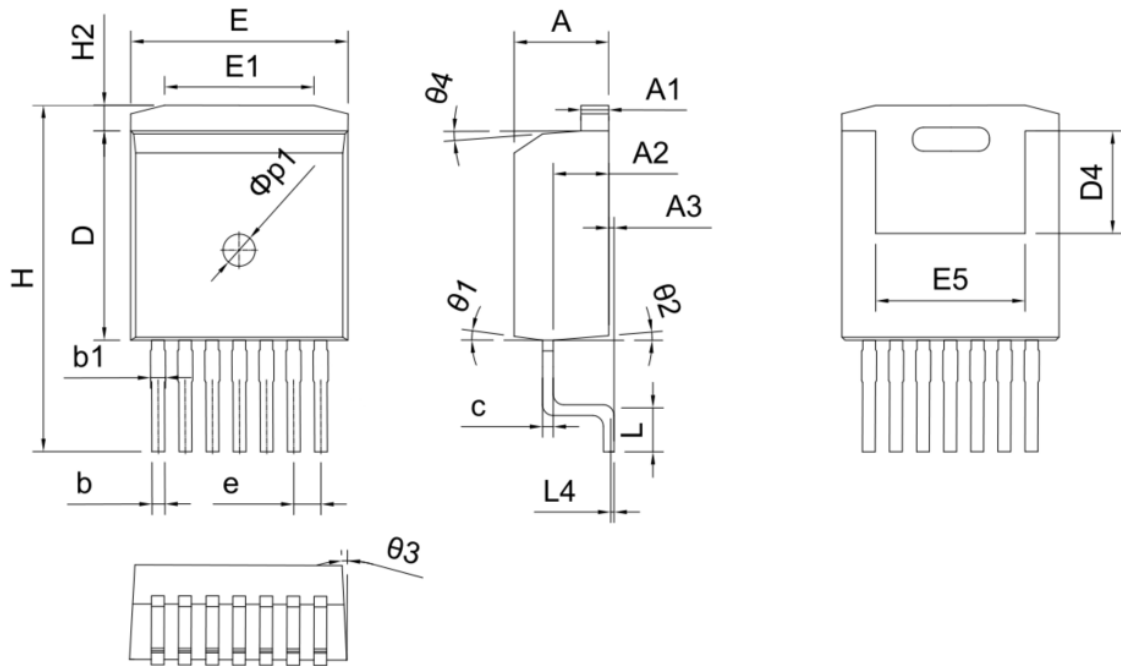


Fig.14 Transient Thermal Impedance (Junction – Case)



Package Dimensions



SYMBOL	mm		
	MIN	NOM	MAX
A	4.30	4.43	4.56
A1	1.20	1.30	1.40
A2	2.45	2.60	2.75
A3	0.00	0.13	0.25
b	0.50	0.60	0.70
b1	0.60	0.70	0.90
c	0.45	0.50	0.60
D	8.93	9.08	9.23
D4	4.65	4.80	4.95
E	10.08	10.18	10.28
E1	6.50	7.00	7.50
E5	6.82	7.22	7.62
e	1.27 BSC		
H	15.00	15.50	16.00
H2	0.98	1.20	1.42
L	1.90	2.20	2.50
L4	0.25 BSC		
$\phi p1$	1.40	1.50	1.60
$\theta 1$	3°	5°	7°
$\theta 2$	3°	5°	7°
$\theta 3$	3°	5°	7°
$\theta 4$	3°	5°	7°

## Ordering Information

Part	Package	Marking	Packing method
WSCM01KMA170T2C	TO-263-7L	1KMA170T2C	Tape and Reel


## Contact Information

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## Product Specification Statement

1.The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

2.The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. WAYON shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and WAYON assumes no responsibility for the application of the product.

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5.The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. WAYON shall assume no responsibility for any consequences resulting from such usage.

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